

SCHOTTKY RECTIFIER

8 Amp

Major Ratings and Characteristics

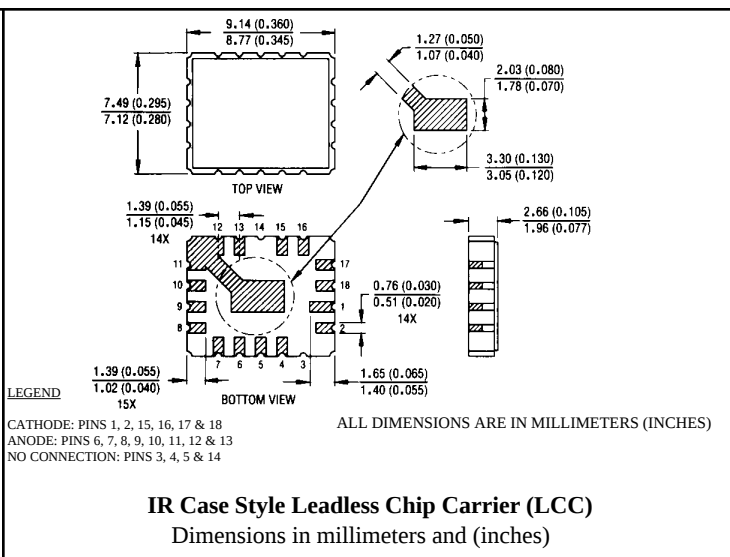
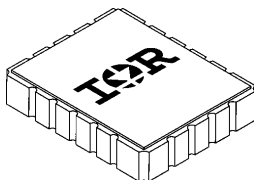
Characteristics	5EQ100	Units
$I_{F(AV)}$ Rectangular waveform	8	A
V_{RRM}	100	V
I_{FSM} @ $t_p = 8.3ms$ sine	250	A
V_F @ 8Apk, $T_J = 125^\circ C$	0.65	V
T_J, T_{stg} Operating and storage	-55 to 150	$^\circ C$

Description/Features

The 5EQ100 Schottky rectifier has been expressly designed to meet the rigorous requirements of hi-rel environments. It is packaged in the hermetic surface mount LCC ceramic package and has extremely low reverse leakage at high temperature. Full MIL-PRF-19500 quality conformance testing is available on source controlled drawings to JANTX, JANTXV, or JANS levels. Typical applications include switching power supplies and resonant power converters.

- Hermetically sealed
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Surface Mount
- Small Footprint
- Lightweight

CASE STYLE



Voltage Ratings

Part number	5EQ100
V_R Max. DC Reverse Voltage (V)	100
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	5EQ100	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current See Fig. 4	8	A	50% duty cycle @ $T_C = 100^\circ\text{C}$, rectangular waveform
I_{FSM} Max. Peak One Cycle Non - Repetitive Surge Current	250	A	@ $t_p = 8.3$ ms sine

Electrical Specifications

Parameters	5EQ100	Units	Conditions
V_{FM} Max. Forward Voltage Drop See Fig. 1 ①	0.80	V	@ 8A $T_J = 25^\circ\text{C}$
	1.00	V	@ 16A
	0.65	V	@ 8A $T_J = 125^\circ\text{C}$
	0.70	V	@ 16A
I_{RM} Max. Reverse Leakage Current See Fig. 2 ①	0.50	mA	$T_J = 25^\circ\text{C}$ $V_R = \text{rated } V_R$
	15	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	600	pF	$V_R = 5V_{DC}$, (test signal range 100KHz to 1MHz) 25°C
L_S Typical Series Inductance	4.3	nH	Measured lead to lead 5mm from package body

Thermal-Mechanical Specifications

Parameters	5EQ100	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance, Junction to Case	6.0	$^\circ\text{C/W}$	DC operation See Fig. 5
wt Weight (Typical)	0.42	g	
Die Description (Square)	0.125	inches	
Case Style	LCC		

① Pulse Width < 300 μs , Duty Cycle < 2%

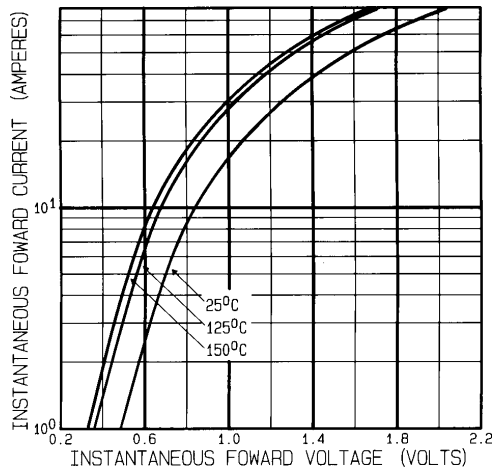


Fig. 1 - Max. Forward Voltage Drop Characteristics

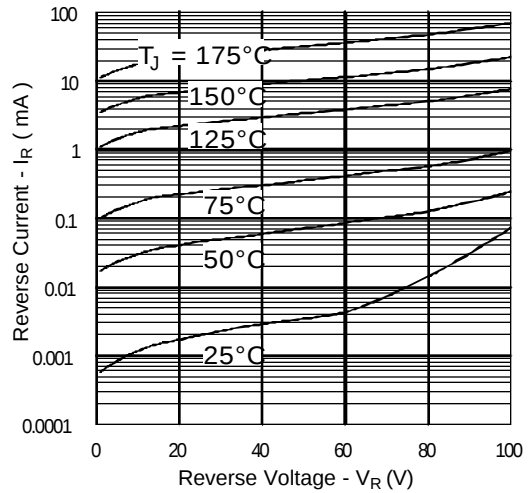


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

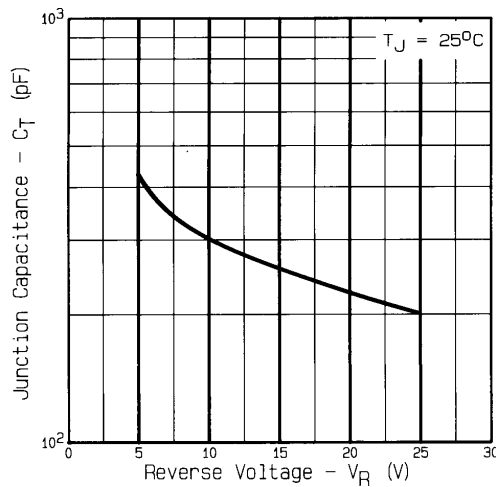


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

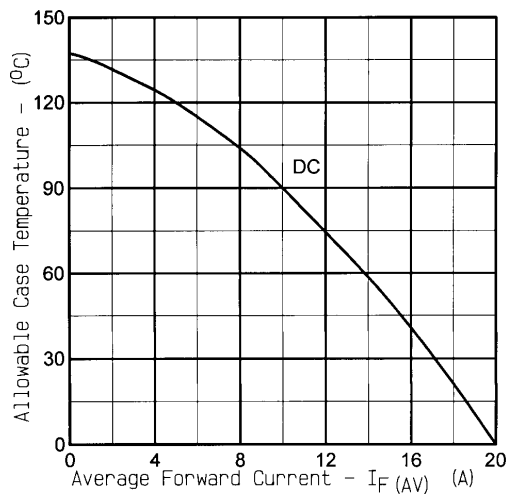
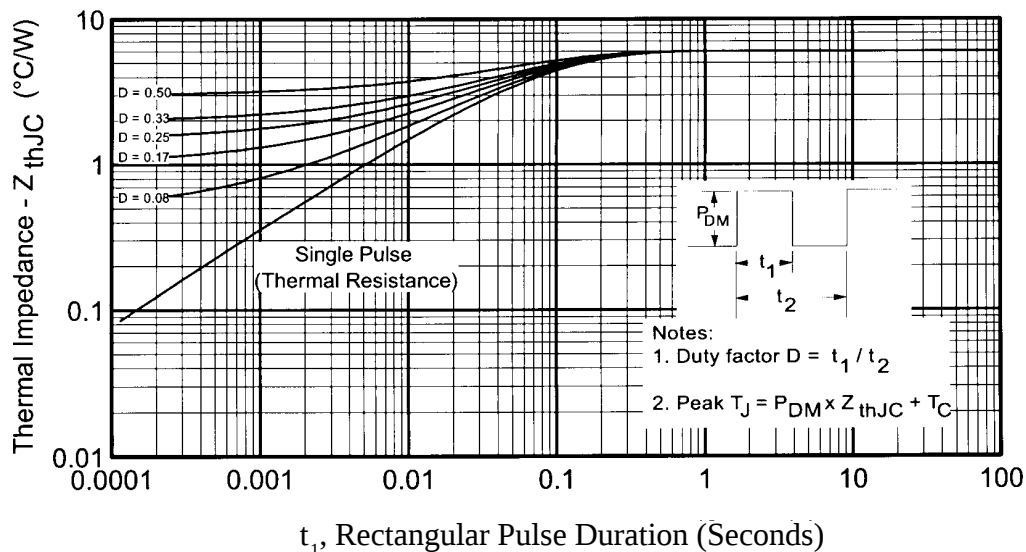


Fig. 4 - Max. Allowable Case Temperature Vs. Average Forward Current

Fig.5 - Max. Thermal Impedance Z_{thJC} characteristics (Per Leg)International
IOR Rectifier**WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245, Tel: (310) 322 3331**EUROPEAN HEADQUARTERS:** Hurst Green, Oxted, Surrey RH8 9BB, UK Tel: ++ 44 1883 732020**IR CANADA:** 7321 Victoria Park Ave., Suite 201, Markham, Ontario L3R 2Z8, Tel: (905) 475 1897**IR GERMANY:** Saalburgstrasse 157, 61350 Bad Homburg Tel: ++ 49 6172 96590**IR ITALY:** Via Liguria 49, 10071 Borgaro, Torino Tel: ++ 39 11 451 0111**IR FAR EAST:** K&H Bldg., 2F, 30-4 Nishi-Ikebururo 3-Chome, Toshima-Ku, Tokyo Japan 171 Tel: 81 3 3983 0086**IR SOUTHEAST ASIA:** 315 Outram Road, #10-02 Tan Boon Liat Building, Singapore 0316 Tel: 65 221 8371<http://www.irf.com/Data> and specifications subject to change without notice. 11/96